

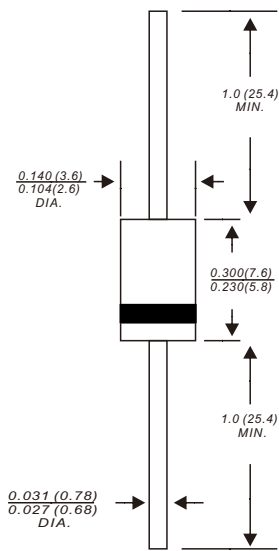


# 1N5391 THRU 1N5399

## GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.5Amperes

### DO-15



Dimensions in inches and (millimeters)

### FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 260 °C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-15 molded plastic body

**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.014 ounce, 0.40 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	1N 5391	1N 5392	1N 5393	1N 5394	1N 5395	1N 5396	1N 5397	1N 5398	1N 5399	UNITS
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	210	280	350	420	560	700	VOLTS
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at T <sub>A</sub> =75 °C	I <sub>(AV)</sub>	1.5									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50.0									Amps
Maximum instantaneous forward voltage at 1.5A	V <sub>F</sub>	1.4									Volts
Maximum DC reverse current T <sub>A</sub> =25 °C at rated DC blocking voltage T <sub>A</sub> =100 °C	I <sub>R</sub>	5.0 50.0									uA
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	20.0									pF
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	50.0									°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175									°C

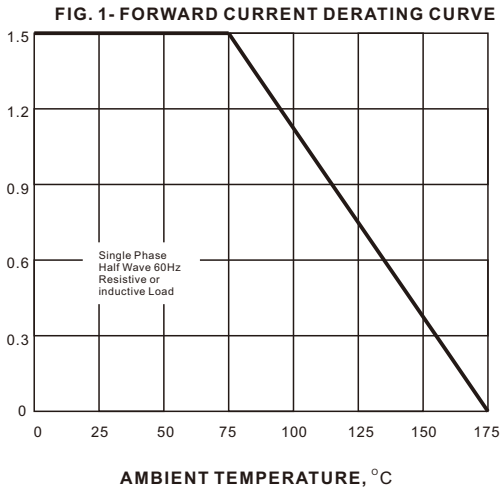
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

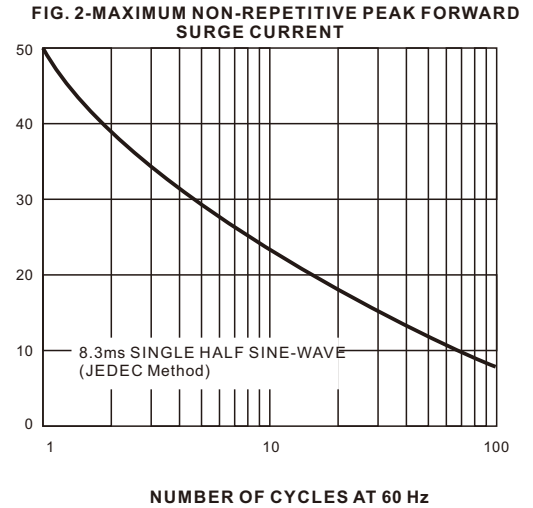


### RATINGS AND CHARACTERISTIC CURVES 1N5391 THRU 1N5399

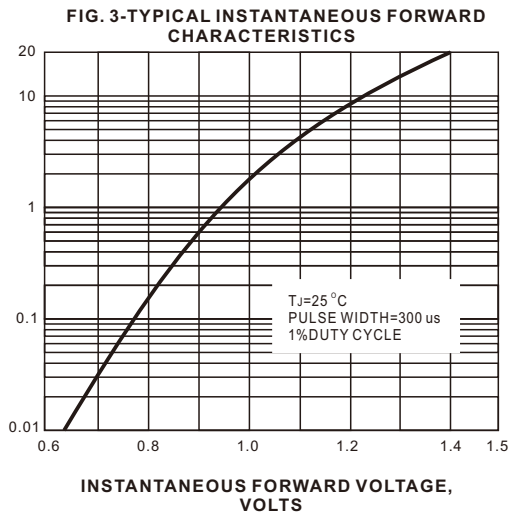
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



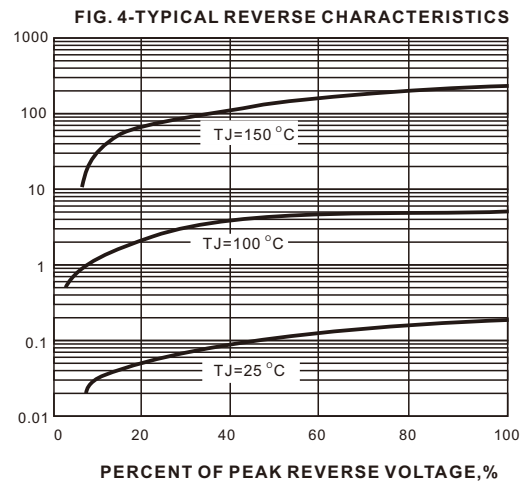
PEAK FORWARD SURGE CURRENT, AMPERES



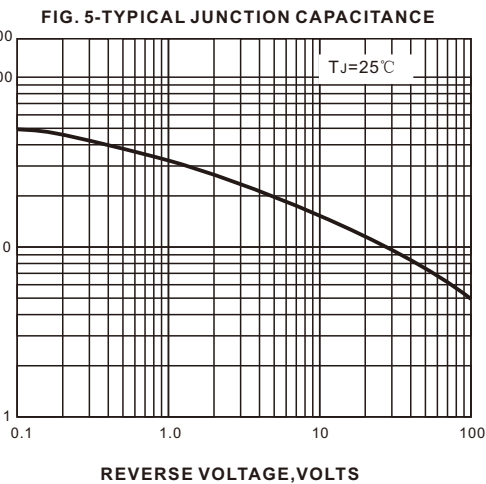
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MICROAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W

